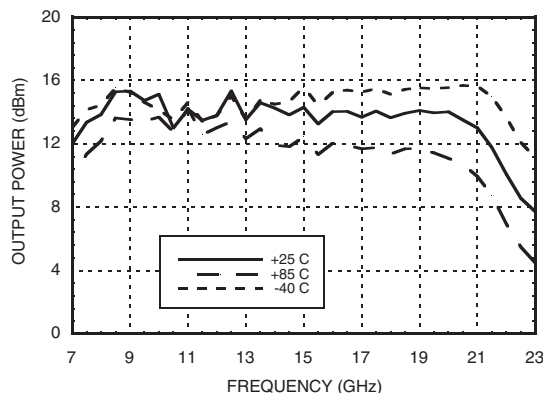
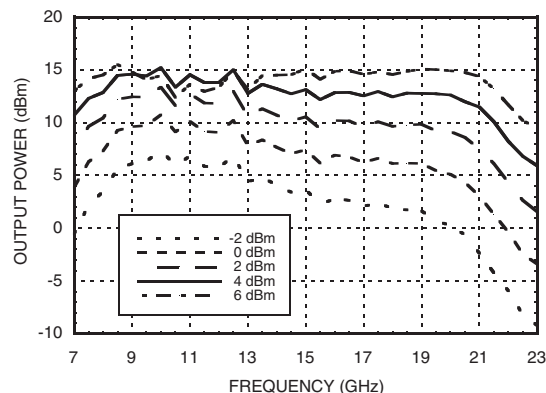
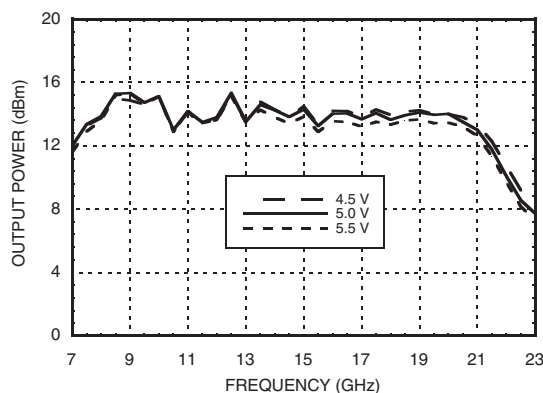
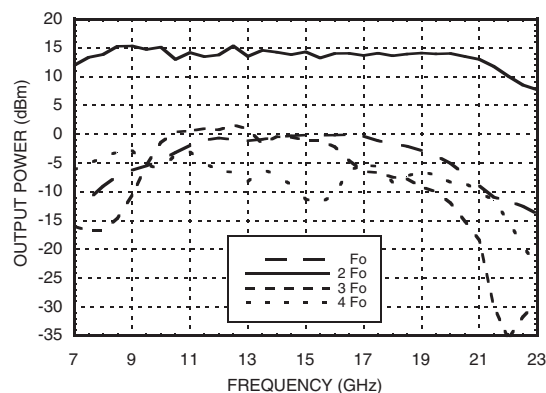
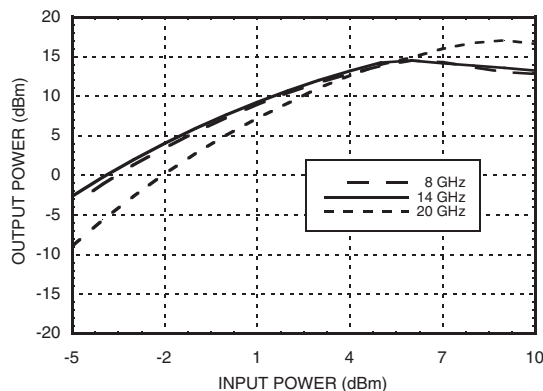
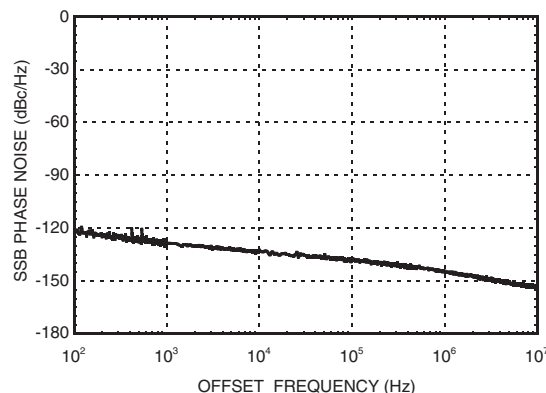
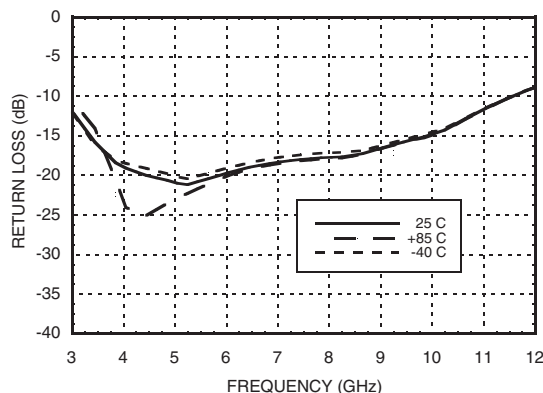
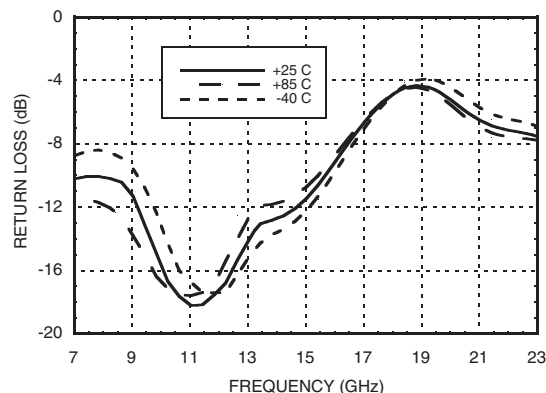
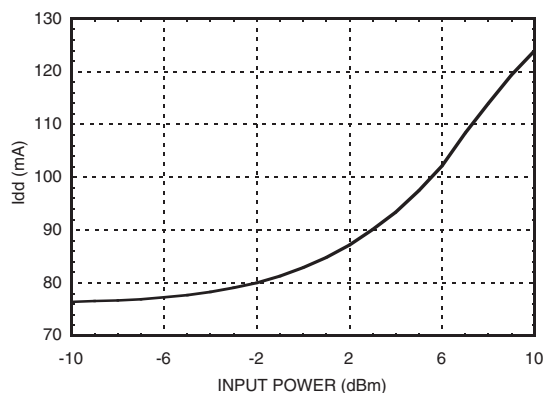


**SMT GaAs MMIC x2 ACTIVE FREQUENCY
MULTIPLIER, 8 - 21 GHz OUTPUT**

**Output Power vs.
Temperature @ 5 dBm Drive Level**

Output Power vs. Drive Level

**Output Power vs.
Supply Voltage @ 5 dBm Drive Level**

Isolation @ 5 dBm Drive Level

Output Power vs. Input Power

**SSB Phase Noise Performance,
Fout= 16 GHz, Input Power = +3 dBm**



**SMT GaAs MMIC x2 ACTIVE FREQUENCY
MULTIPLIER, 8 - 21 GHz OUTPUT**
Input Return Loss vs. Temperature

Output Return Loss vs. Temperature

Supply Current vs. Input Power

Absolute Maximum Ratings

RF Input (Vdd = +5V)	+10 dBm
Supply Voltage (Vdd)	+5.5 Vdc
Channel Temperature	150 °C
Continuous P _{diss} (T= 85 °C) (derate 9.8 mW/°C above 85 °C)	635 mW
Thermal Resistance (channel to ground paddle)	102 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vdd

Vdd (Vdc)	Idd (mA)
4.5	97
5.0	98
5.5	99

Note:
Multiplier will operate over full voltage range shown above.

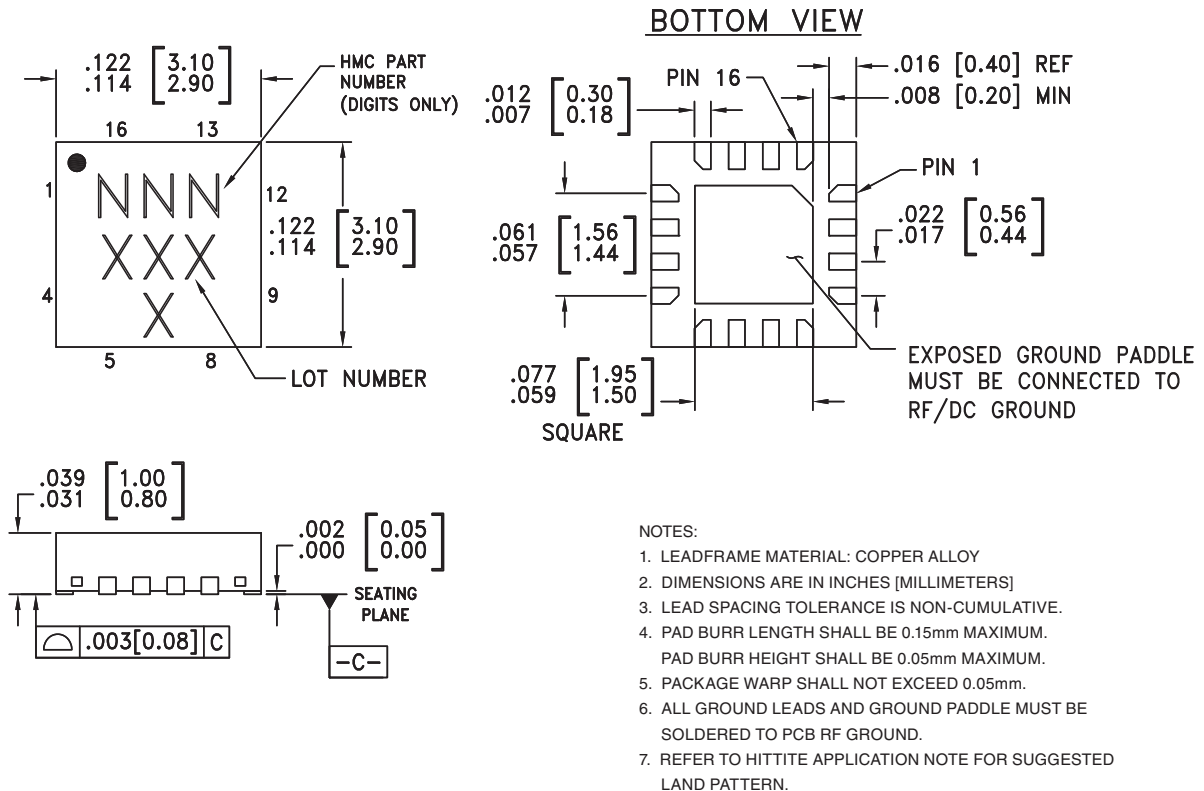


**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 8 - 21 GHz OUTPUT



Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC561LP3	Low Stress Injection Molded Plastic ^[4]	Sn/Pb Solder	MSL1 ^[1]	561 XXXX
HMC561LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	561 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C


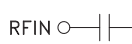
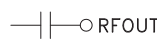
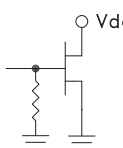

[3] 4-Digit lot number XXXX

[4] For availability on Non-RoHS HMC561LP3 products please contact Hittite Microwave sales directly.

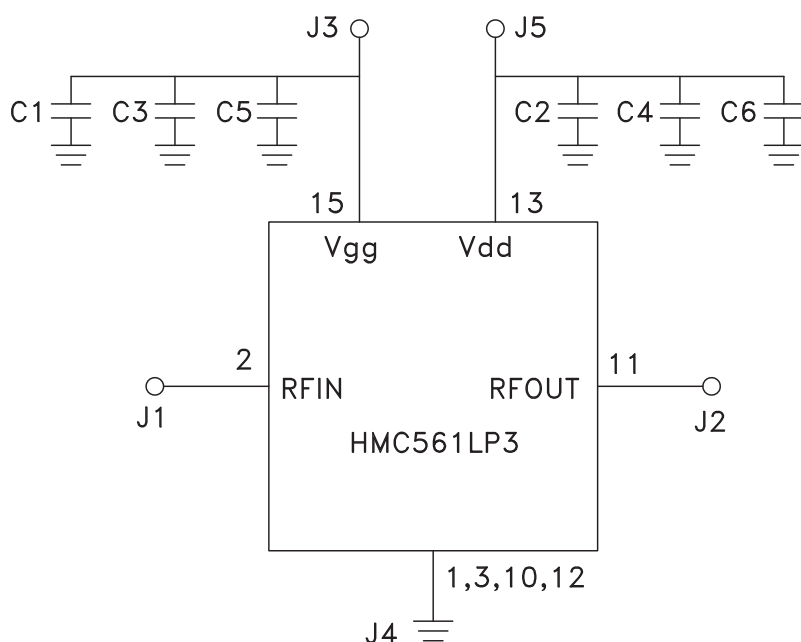
SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 8 - 21 GHz OUTPUT



Pin Description

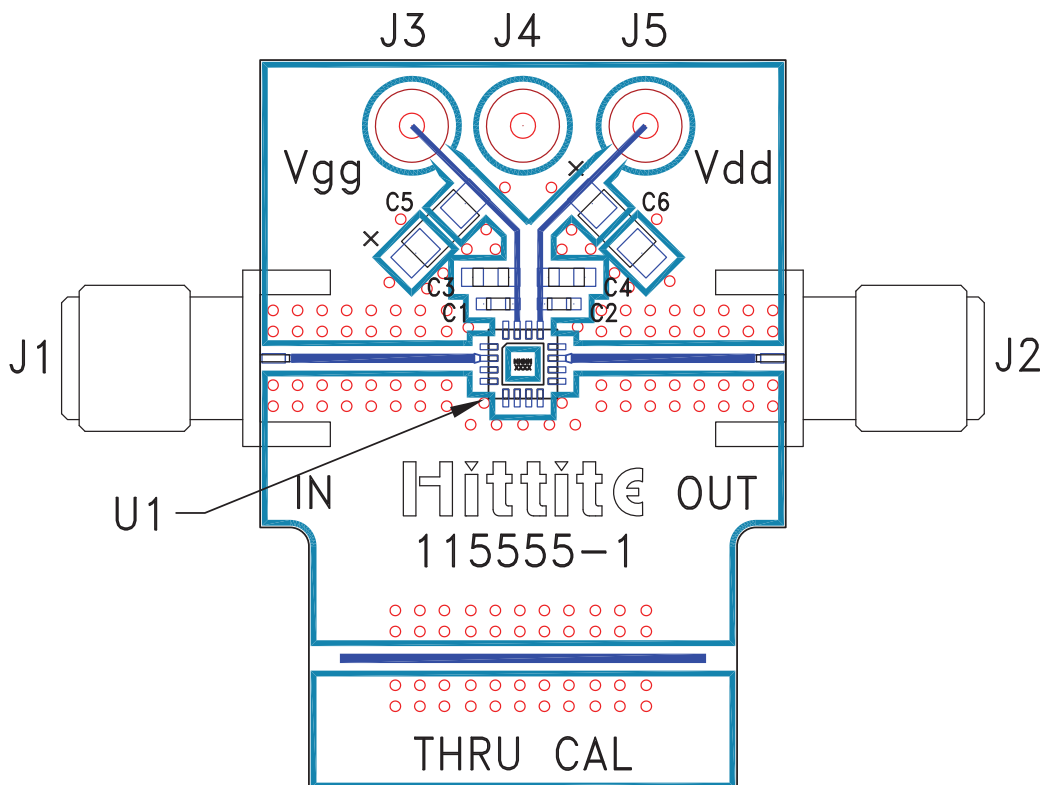
Pin Number	Function	Description	Interface Schematic
1, 3, 10, 12	GND	Package bottom must also be connected to RF/DC ground.	
2	RFIN	Pin is AC coupled and matched to 50 Ohms.	
4 - 9, 14, 16	N/C	These pins are internally not connected; however, this product was specified with these pins connected to RF/DC ground.	
11	RFOUT	Pin is AC coupled and matched to 50 Ohms.	
13	Vdd	Supply voltage 5V ± 0.5V. External bypass capacitors of 100 pF, 1,000 pF and 2.2 µF are required.	
15	Vgg	Gate control for multiplier. Adjust to achieve Idd of 98 mA. Please follow "MMIC Amplifier Biasing Procedure" Application note.	

Application Circuit



Component	Value
C1, C2	100 pF
C3, C4	1,000 pF
C5, C6	2.2 µF

**SMT GaAs MMIC x2 ACTIVE FREQUENCY
MULTIPLIER, 8 - 21 GHz OUTPUT**

Evaluation PCB

List of Materials for Evaluation PCB 115556 [1]

Item	Description
J1, J2	PCB Mount SRI K Connector
J3 - J5	DC Pin
C1, C2	100 pF Capacitor, 0402 Pkg.
C3, C4	1,000 pF Capacitor, 0603 Pkg.
C5, C6	2.2 μ F Tantalum Capacitor
U1	HMC561LP3E x2 Active Multiplier
PCB [2]	115555 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.